

Goal:

To characterize the deposition rates of platinum within the Explorer 14 as a function of supplied power and gas pressure, and the resulting film stress.

Materials:

- Platinum target
- Diamond Scribe/Cleaver
- Acetone
- 3 inch Patterned Silicon Wafers
- 4 inch Silicon Wafers

Equipment:

- Explorer 14 Magnetron Sputterer
- KLA Stress Profilometer

Units:

- Pressure: milliTorr (mT)
- Cathode Power: Watts
- Time: Seconds (s)
- Stress: MegaPascals (MPa)
- Thickness: nanometers (nm)

Protocol:

Pre Measurement

Pre Measurement steps are noted in the *Measurement of residual stress in deposited films* document in the *Pre-Deposition wafer bow measurement* section.

Deposition

- 1. Cleave 3 samples from the 3 inch patterned silicon wafer
- 2. Orient the wafer and sample pieces on opposite ends of the plate, as seen in Fig.1
- 3. Deposit platinum onto the 4 inch wafer and three sample pieces

Post Measurement

Post Measurement steps are noted in the *Measurement of residual stress in deposited films* document in the *Post-Deposition film thickness measurement* & the *Post-Deposition Wafer bow measurement and stress calculation* sections.



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Fig.1. The general orientation of the 4 inch wafer and the samples from the 3 inch wafer. Note the positioning, which, due to the rotation of the plate, allow the samples to map to the different positions of the wafer (Major flat, Center, and Far from Major Flat)

Results:

The goal of this study was to obtain an understanding of the stress and thickness properties of a deposited platinum film at varying powers and pressures. Towards this end, depositions were done by varying the cathode power and gas pressure while depositing for 180 seconds. From this data, predictions can be made about how the deposition rates and stresses of the film vary with gas pressure and cathode power.

The following results were obtained using cathode powers of 400W, 450W, and 500W, as well as having gas pressures of 3 mTorr, 5mTorr, 7 mTorr, 8 mTorr, and 10 mTorr for each power setting. Fig.2 denotes the deposition rates as a function of supplied power and gas pressure with relevant data being in Table 1. Fig.3 denotes the stress trend that was obtained from the deposited films.

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Fig. 2. The deposition rate of platinum (nm/min) as a function of gas pressure and cathode power. Each point is an average of measurements taken from representative samples of the major flat, center, and far end of the substrate.

| | 3mTorr | 5mTorr | 7mTorr | 8mTorr | 10mTorr |
|------|----------|----------|----------|----------|----------|
| 400W | 26.28889 | 27.54444 | 28.03704 | 28.12222 | 29.05185 |
| 450W | 29.27407 | 31.08519 | 31.1037 | 32.04815 | 32.23704 |
| 500W | 31.94444 | 34.37778 | 34.47407 | 34.17037 | 34.96667 |

Table.1. The (averaged) values of the platinum deposition rates (nm/min) for different cathode power values and different pressure

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Fig. 3. The film stress (MPa) as a function of gas pressure (mTorr).

| Power | 3mTorr | 5mTorr | 7mTorr | 8mTorr | 10mTorr |
|-------|--------|--------|--------|--------|---------|
| 400W | -772.2 | -758.7 | -732.2 | -691.7 | -758.7 |
| 450W | -765.8 | -714.6 | -776.3 | -744.4 | -752.2 |
| 500W | -732.3 | -718.6 | -716.7 | -699.7 | -793.1 |

Table 2. The (Average) values of the film stress (MPa) for differing values ofcathode power and gas pressure.

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Discussion:

In Fig.2, note that the deposition rate increases both as a function of cathode power and gas pressure. Also, the amount of uncertainty that is attached to these values are in the range of 1.5-2.5 nm/min. The general trend of platinum's behavior here has also been observed in a paper by NASA (see: https://www.grc.nasa.gov/WWW/sensors/PhySen/docs/TM-2005-213433.pdf)

In Table.1, the values are averaged from three data points taken from each of the three samples.

In Fig.3, note that the film stress values are negative, because platinum is a compressive film, which contracts and bends upwards. Also note that the stress of the film lies essentially within the bounds of -690 to -795 MPa, or essentially -742.5±52.5. From the analysis which is discussed in Error propagation for Substrate Thickness post-deposition (Stoney Equation Analysis), it can be verified that the uncertainties that are associated with each stress point would indeed overlap, giving a general view of what the stress of the film upon the substrate would be.

| Sample # | Major Flat Measures (nm) | | sures (nm) | Center Measures (nm) | | Furthest from MF (nm) | | | MEAN | STD | ERROR | |
|----------|--------------------------|------|------------|----------------------|-------|-----------------------|-------|-------|-------|----------|----------|----------|
| 21 | 60 | 59.7 | 59 | 83.1 | 83.2 | 83 | 93 | 94.5 | 94.3 | 78.86667 | 14.35316 | 4.784388 |
| 22 | 64.6 | 64.6 | 63.1 | 87.1 | 91.5 | 82.8 | 101.5 | 100.1 | 101.7 | 84.11111 | 15.40371 | 5.13457 |
| 23 | 72.3 | 67.8 | 65.8 | 94 | 91.6 | 87.2 | 100.7 | 102.5 | 102.5 | 87.15556 | 14.03307 | 4.677688 |
| 24 | 65.7 | 63.5 | 60.3 | 84 | 87.4 | 86.3 | 99.5 | 98.6 | 98.4 | 82.63333 | 14.82355 | 4.941185 |
| 25 | 62 | 65.4 | 62.3 | 85.3 | 87.2 | 88.9 | 103.1 | 99.1 | 106 | 84.36667 | 16.37206 | 5.457354 |
| 26 | 65.9 | 49.8 | 66.7 | 95.5 | 93.4 | 96.5 | 107.8 | 107.2 | 107.6 | 87.82222 | 20.28561 | 6.761872 |
| 27 | 66.6 | 65.7 | 70.8 | 100 | 98.2 | 103.6 | 110 | 112.1 | 112.3 | 93.25556 | 18.70592 | 6.235306 |
| 28 | 69.1 | 66.7 | 71 | 97.2 | 98.7 | 99.7 | 111.5 | 112.8 | 113.1 | 93.31111 | 18.19447 | 6.064824 |
| 29 | 67.2 | 71.3 | 75.2 | 103 | 102.4 | 99.4 | 116 | 114.4 | 116.4 | 96.14444 | 18.6435 | 6.214501 |
| 30 | 74.2 | 72.9 | 71.4 | 102.8 | 101.1 | 98.1 | 116.2 | 116.6 | 117.1 | 96.71111 | 18.14671 | 6.048904 |
| 31 | 68.3 | 69.6 | 72.9 | 99.3 | 98 | 102.8 | 118.5 | 115.6 | 117.5 | 95.83333 | 19.46906 | 6.489688 |
| 32 | 81.5 | 78.6 | 76.8 | 107.1 | 109.7 | 111.6 | 121.5 | 121 | 120.4 | 103.1333 | 17.79063 | 5.930211 |
| 33 | 78.9 | 78.8 | 76.2 | 110.7 | 107.7 | 107.4 | 124 | 122.8 | 124.3 | 103.4222 | 19.06292 | 6.354308 |
| 34 | 71.4 | 74.8 | 76.8 | 105.1 | 107.1 | 109.1 | 125.8 | 124.2 | 128.3 | 102.5111 | 21.46286 | 7.154286 |
| 35 | 83.5 | 77.6 | 74.8 | 109.6 | 109.6 | 108.6 | 128 | 125.4 | 127 | 104.9 | 20.02609 | 6.675365 |
| | | | | | | | | | | | | |

Additional Data:

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Table.2. The raw data for the film thicknesses for the platinum depositions. Each column under the major flat, center, and furthest from major flat represent one of the three measurements taken from that area of interest.

| Power (W)/ | MFD Average | MFD Max | MFD Center | MFR Average | MFR Max | MFR Center |
|------------------|-------------|---------|------------|-------------|---------|------------|
| Pressure (mTorr) | (MPA) | (MPa) | (MPa) | (MPa) | (MPa) | (MPa) |
| 400 W/3 mTorr | -772.2 | -1100 | -655.9 | -815.9 | -1278 | -752.5 |
| 400 W/7 mTorr | -732.2 | -897.8 | -706.1 | -777.3 | -810.9 | -805.7 |
| 400 W/10 mTorr | -775.3 | -815.5 | -808 | -786.5 | -861.6 | -849.6 |
| 400 W/5 mTorr | -758.7 | -794.1 | -766.9 | -750.5 | -1060 | -744.2 |
| 400 W/8 mTorr | -691.7 | -1203 | -986.5 | -911.1 | -1578 | -1130 |
| 450 W/3 mTorr | -765.8 | -942.4 | -753.4 | -757.3 | -864.2 | -770.4 |
| 450 W/5 mTorr | -714.6 | -726.4 | -717 | -748.8 | -835.5 | -751.2 |
| 450 W/7 mTorr | -776.3 | -796.3 | -767.8 | -803.7 | -898.6 | -813.7 |
| 450 W/8 mTorr | -744.4 | -753 | -749.1 | -776 | -918.2 | -782.2 |
| 450 W/10 mTorr | -752.2 | -762.3 | -748.9 | -793.6 | -885.2 | -800.6 |
| 500 W/3 mTorr | -732.3 | -826.4 | -725.6 | -757.6 | -868.4 | -756 |
| 500 W/5 mTorr | -718.6 | -839 | -699.6 | -724.9 | -787.4 | -752.3 |
| 500 W/7 mTorr | -716.7 | -742.2 | -720.5 | -740.7 | -811.2 | -751.4 |
| 500 W/8 mTorr | -699.7 | -738.8 | -691.8 | -800.1 | -843.7 | -807.1 |
| 500 W/10 mTorr | -793.1 | -853.4 | -793.3 | -789.2 | -844.3 | -811.1 |

Table.3. The raw data of the stress measurements across the wafers, where MFD refers to major flat facing down, and MFR refers to major flat facing towards the right inside the profilometer. For the stress measurements and graphs, the average values were utilized.